









SN54ACT241, SN74ACT241

SCAS516E - JUNE 1995 - REVISED MARCH 2024

## SNx4ACT241 Octal Buffers/Drivers with 3-State Outputs

#### 1 Features

- Operation of 4.5V to 5.5V V<sub>CC</sub>
- Inputs accept voltages to 5.5V
- Max t<sub>pd</sub> of 8.5ns at 5V
- Inputs are TTL-compatible

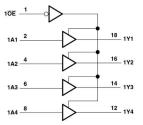
## 2 Description

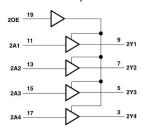
These octal buffers and line drivers are designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE(2)	BODY SIZE(3)
	N (PDIP, 20)	24.33mm × 9.4mm	24.33mm × 6.35mm
	DW (SOIC, 20)	12.8mm × 10.3mm	12.8mm × 7.5mm
SNx4ACT241	NS (SOP, 20)	12.6mm × 7.8mm	12.6mm × 5.3mm
	DB (SSOP, 20)	7.2mm × 7.8mm	7.2mm × 5.3mm
	PW (TSSOP, 20)	6.5mm × 6.4mm	6.5mm × 4.4mm

- For more information, see Section 10.
- The package size (length × width) is a nominal value and (2) includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.





Logic Diagram (Positive Logic)

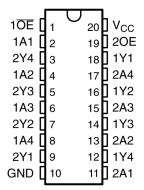


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## 3 Pin Configuration and Functions



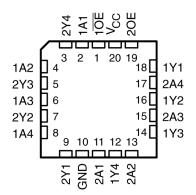


Figure 3-1. SN54ACT241 J or W Package SN74ACT241 DB, DW, N, NS, or PW Package (Top View)

Figure 3-2. SN54ACT241 FK Package (Top View)

**Table 3-1. Pin Functions** 

NAME1	PIN	TYPE	DESCRIPTION
10E	1	I	Output enable 1
1A1	2	I	1A1 input
2Y4	3	0	2Y4 output
1A2	4	I	1A2 input
2Y3	5	0	2Y3 output
1A3	6	I	1A3 input
2Y2	7	0	2Y2 output
1A4	8	I	1A4 input
2Y1	9	0	2Y1 output
GND	10	_	Ground pin
2A1	11	I	2A1 input
1Y4	12	0	1Y4 output
2A2	13	I	2A2 input
1Y3	14	0	1Y3 output
2A3	15	I	2A3 input
1Y2	16	0	1Y2 output
2A4	17	I	2A4 input
1Y1	18	0	1Y1 output
20E	19	I	Output enable 2
VCC	20	_	Power pin



## 4 Specifications

## 4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
V <sub>I</sub> (2)	Input voltage range		-0.5	V <sub>CC</sub> +0.5	V
V <sub>O</sub> (2)	Output voltage range	-0.5	V <sub>CC</sub> +0.5	V	
I <sub>IK</sub>	Input clamp current	$(V_I < 0 \text{ or } V_I > V_{CC})$		±20	mA
I <sub>OK</sub>	Output clamp current	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
Io	Continuous output current	$(V_O = 0 \text{ or } V_{CC})$		±50	mA
	Continuous current through V <sub>CC</sub> or GND		±200	mA	
T <sub>stg</sub>	Storage temperature range	-65	150	°C	

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### **4.2 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)(1)

		SN54A	SN54ACT241		SN74ACT241		
		MIN	MAX	MIN MAX		UNIT	
V <sub>CC</sub>	Supply voltage	4.5	5.5	4.5	5.5	V	
V <sub>IH</sub>	High-level input voltage	2		2		V	
V <sub>IL</sub>	Low-level input voltage		0.8		0.8	V	
VI	Input voltage	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V	
Vo	Output voltage	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V	
I <sub>OH</sub>	High-level output current		-24		-24	mA	
I <sub>OL</sub>	Low-level output current		24		24	mA	
Δt/Δν	Input transition rise or fall rate		8		8	ns/V	
T <sub>A</sub>	Operating free-air temperature	-55	125	-40	85	°C	

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

#### 4.3 Thermal Information

THERMAL METRIC(1)		DB (SSOP)	DW (SOIC)	N (PDIP)	NS (SOP)	PW (TSSOP)	UNIT
				20 PINS			
$R_{\theta JA}$	Junction-to-ambient thermal resistance <sup>(2)</sup>	70	58	69	60	126.2	°C/W

<sup>1)</sup> For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.



#### 4.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	1	Γ <sub>A</sub> = 25°C		SN54A	CT241	SN74AC	T241	LINUT
PARAMETER	R TEST CONDITIONS		MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	I <sub>OH</sub> = -50 μA	4.5 V	4.4	4.49		4.4		4.4		
	ΙΟΗ50 μΑ	5.5 V	5.4	5.49		5.4		5.4		
V	1 - 24 mA	4.5 V	3.86			3.7		3.76		V
V <sub>OH</sub>	I <sub>OH</sub> = -24 mA	5.5 V	4.86			4.7		4.76		v
	$I_{OH} = -50 \text{ mA}^{(1)}$	5.5 V				3.85				
	$I_{OH} = -75 \text{ mA}^{(1)}$	5.5 V						3.85		
	I <sub>OL</sub> = 50 μA	4.5 V		0.001	0.1		0.1		0.1	
		5.5 V		0.001	0.1		0.1		0.1	
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \		4.5 V			0.36		0.5		0.44	V
V <sub>OL</sub>	I <sub>OL</sub> = 24 mA	5.5 V			0.36		0.5		0.44	V
	I <sub>OL</sub> = 50 mA <sup>(1)</sup>	5.5 V					1.65			
	I <sub>OL</sub> = 75 mA <sup>(1)</sup>	5.5 V							1.65	
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5 V			±0.25		±5		±2.5	μA
I <sub>I</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5.5 V			±0.1		±1		±1	μA
I <sub>CC</sub>	$V_I = V_{CC}$ or $I_O = 0$	5.5 V			4		80		40	μA
ΔI <sub>CC</sub> (2)	One input at 3.4 V, Other inputs at GND or V <sub>CC</sub>	5.5 V		0.6			1.6		1.5	mA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		2.5						pF
Co	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		8						pF

<sup>(1)</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 2 ms.

## 4.5 Switching Characteristics

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	Т	A = 25°C		SN54AC	T241	SN74AC	T241	UNIT
FARAMETER	FROW (INFOT)	10 (001701)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT
t <sub>PLH</sub>	۸	V	1.5	6	8.5	1	9.5	1.5	9.5	no
t <sub>PHL</sub>	Α Α	Ť	1.5	5.5	7.5	1	9	1.5	8.5	ns
t <sub>PZH</sub>	OE or OE	V	1.5	7	8.5	1	10	1	9.5	ns
t <sub>PZL</sub>	OL 01 OL	1	2	7	9.5	1	11.5	1.5	10.5	115
t <sub>PHZ</sub>	OE or OE	V	2	8	9.5	1	11	2	10.5	no
t <sub>PLZ</sub>	OE OI OE	T	2.5	6.5	10	1	11.5	2	10.5	ns

## 4.6 Operating Characteristics

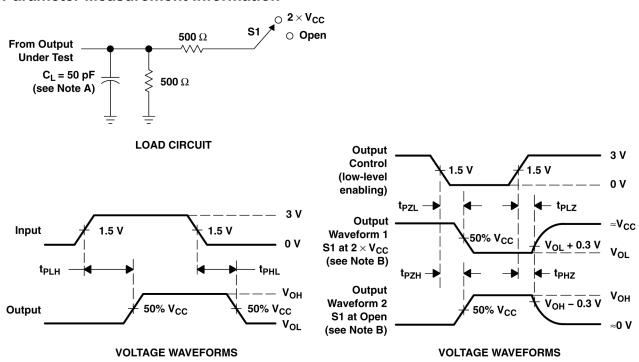
 $V_{CC}$  = 5 V,  $T_A$  = 25°C

PARAMETER		TEST C	TYP	UNIT		
C <sub>pd</sub>	Power dissipation capacitance per buffer/driver		$C_L = 50 pF$ ,	f = 1 MHz	45	pF

<sup>(2)</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V<sub>CC</sub>.



#### **5 Parameter Measurement Information**



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 2.5$  ns,  $t_f \leq 2.5$  ns.
- D. The outputs are measured one at a time with one input transition per measurement.

Figure 5-1. Load Circuit and Voltage Waveforms

TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	2 × V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	Open

### **6 Detailed Description**

## 6.1 Overview

The 'ACT241 devices are organized as two 4-bit buffers/drivers with separate complementary output-enable  $(1\overline{OE}$  and 2OE) inputs. When  $1\overline{OE}$  is low or 2OE is high, the device passes noninverted data from the A inputs to the Y outputs. When  $1\overline{OE}$  is high or 2OE is low, the outputs are in the high-impedance state

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor and OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sinking or the current-sourcing capability of the driver.

### 6.2 Functional Block Diagram

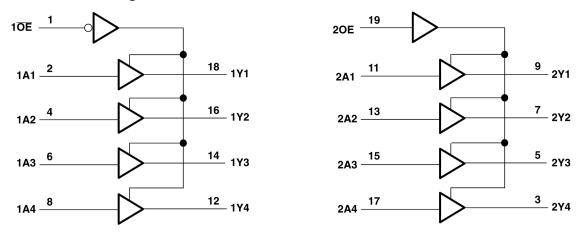


Figure 6-1. Logic Diagram (Positive Logic)

#### **6.3 Device Functional Modes**

#### **Function Tables**

INPL	OUTPUT	
1 <del>OE</del>	1A	1Y
L	Н	Н
L	L	L
Н	X	Z

INPUT	OUTPUT	
20E	2A	2Y
Н	Н	Н
Н	L	L
L	X	Z

## 7 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 7.1 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in Section 4.2.

Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends 0.1  $\mu$ F and if there are multiple  $V_{CC}$  terminals, then TI recommends .01  $\mu$ F or .022  $\mu$ F for each power terminal. It is okay to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1  $\mu$ F and 1  $\mu$ F are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

### 7.2 Layout

#### 7.2.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$  whichever make more sense or is more convenient. It is generally okay to float outputs unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This does not disable the input section of the IOs so they cannot float when disabled.

#### 7.2.1.1 Layout Example

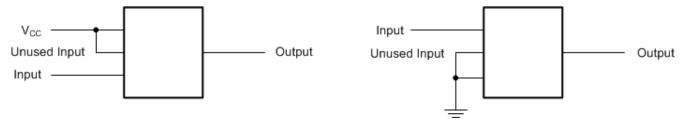


Figure 7-1. Layout Recommendation



## 8 Device and Documentation Support

## 8.1 Documentation Support

#### 8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN54ACT241	Click here	Click here	Click here	Click here	Click here	
SN74ACT241	Click here	Click here	Click here	Click here	Click here	

#### 8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 8.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 8.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 9 Revision History

#### 

#### Changes from Revision C (October 2002) to Revision D (May 2023)

Page

Added Package Information table, Pin Functions table, and Thermal Information table......



## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-89847012A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 89847012A SNJ54ACT 241FK	Samples
5962-8984701RA	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8984701RA SNJ54ACT241J	Samples
5962-8984701SA	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8984701SA SNJ54ACT241W	Samples
SN74ACT241DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AD241	Samples
SN74ACT241DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85	ACT241	
SN74ACT241DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ACT241	Samples
SN74ACT241N	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74ACT241N	Samples
SN74ACT241NSR	ACTIVE	SOP	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ACT241	Samples
SN74ACT241PW	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 85	AD241	
SN74ACT241PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AD241	Samples
SNJ54ACT241FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 89847012A SNJ54ACT 241FK	Samples
SNJ54ACT241J	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8984701RA SNJ54ACT241J	Samples
SNJ54ACT241W	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8984701SA SNJ54ACT241W	Samples

<sup>&</sup>lt;sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

## PACKAGE OPTION ADDENDUM

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(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN54ACT241, SN74ACT241:

Catalog: SN74ACT241

Military: SN54ACT241

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

## **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

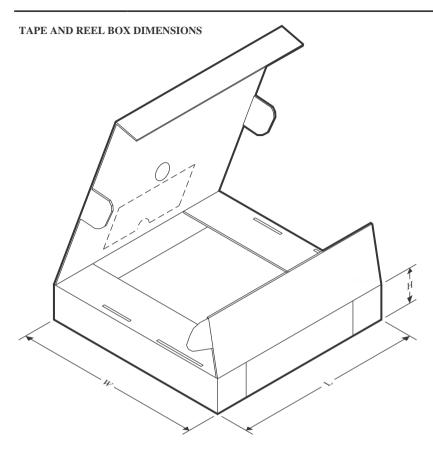


#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ACT241DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74ACT241DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74ACT241NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74ACT241PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74ACT241PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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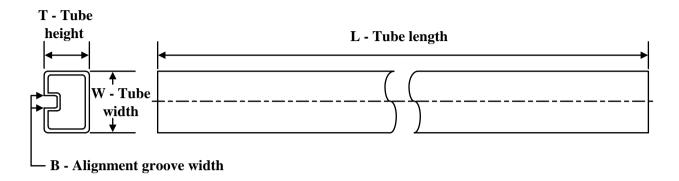
\*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ACT241DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74ACT241DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74ACT241NSR	SOP	NS	20	2000	367.0	367.0	45.0
SN74ACT241PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74ACT241PWR	TSSOP	PW	20	2000	353.0	353.0	32.0

## **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-89847012A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-8984701SA	W	CFP	20	25	506.98	26.16	6220	NA
SN74ACT241N	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54ACT241FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54ACT241W	W	CFP	20	25	506.98	26.16	6220	NA

## 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# W (R-GDFP-F20)

## CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.

  D. Index point is provided on cap for terminal identification only.

  E. Falls within Mil—Std 1835 GDFP2—F20







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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